

17th Russian Youth Conference on Physics of Semiconductors and Nanostructures, Opto- and Nanoelectronics (RYCPS 2015)

Journal of Physics: Conference Series Volume 690

St. Petersburg, Russia
23 – 27 November 2015

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ISBN: 978-1-5108-2235-1
ISSN: 1742-6588

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23–27 November 2015, St. Petersburg, Russia**

Accepted papers received: 1 February 2016

Published online: 26 February 2016

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